

International
IOR Rectifier

10BQ030PbF

SCHOTTKY RECTIFIER

1 Amp

$$I_{F(AV)} = 1.0\text{Amp}$$

$$V_R = 30\text{V}$$

Major Ratings and Characteristics

Characteristics	Value	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 5\text{ms}$ sine	430	A
V_F @ 1.0Apk , $T_J = 125^\circ\text{C}$	0.30	V
T_J range	- 55 to 150	$^\circ\text{C}$

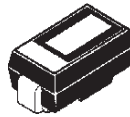
Description/ Features

The 10BQ030PbF surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

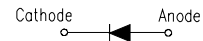
- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free ("PbF" suffix)

Case Styles

10BQ030PbF



SMB



Voltage Ratings

Part number	10BQ030PbF
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	10BQ	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	1.0	A	50% duty cycle @ $T_L = 106^\circ\text{C}$, rectangular wave form.
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	430	V	5 μs Sine or 3 μs Rect. pulse
	90		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	3.0	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1\text{A}$, $L = 6\text{mH}$
I_{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_a = 1.5 \times V_r$ typical

Electrical Specifications

Parameters	10BQ	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1)	0.420	V	@ 1A
	0.470	V	@ 2A
V_{FM} Max. Forward Voltage Drop (1)	0.300	V	@ 1A
	0.370	V	@ 2A
I_{RM} Max. Reverse Leakage Current (1)	0.5	mA	$T_J = 25^\circ\text{C}$
	5.0	mA	$T_J = 100^\circ\text{C}$
	15	mA	$T_J = 125^\circ\text{C}$
C_T Max. Junction Capacitance	200	pF	$V_R = 5V_{DC}$ (test signal range 100KHz to 1Mhz) 25°C
L_S Typical Series Inductance	2.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs	

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	10BQ	Units	Conditions
T_J Max. Junction Temperature Range (*)	-55 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
R_{thJL} Max. Thermal Resistance Junction to Lead (**)	25	$^\circ\text{C}/\text{W}$	DC operation
R_{thJA} Max. Thermal Resistance Junction to Ambient	80	$^\circ\text{C}/\text{W}$	
wt Approximate Weight	0.10(0.003)	g(oz.)	
Case Style	SMB		Similar DO-214AA
Device Marking	IR1E		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

(**) Mounted 1 inch square PCB

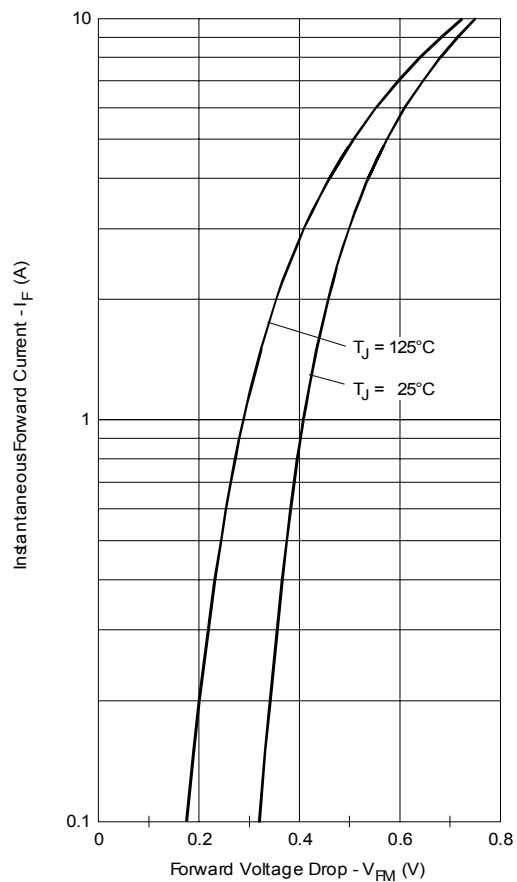


Fig. 1 - Maximum Forward Voltage Drop Characteristics

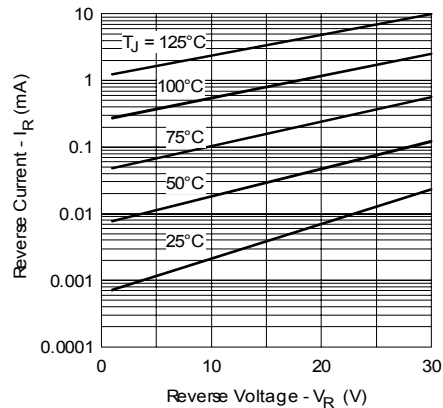


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

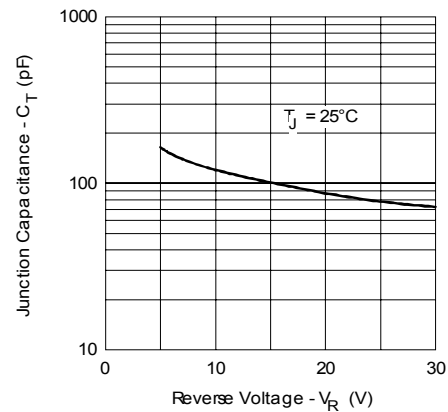


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

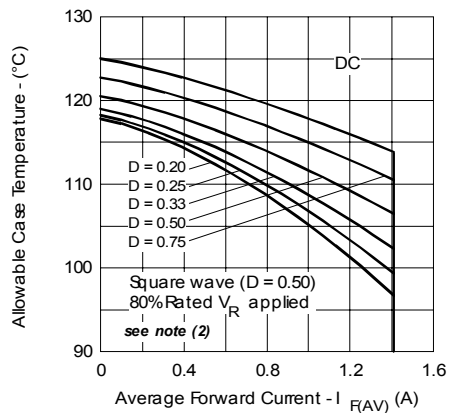


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

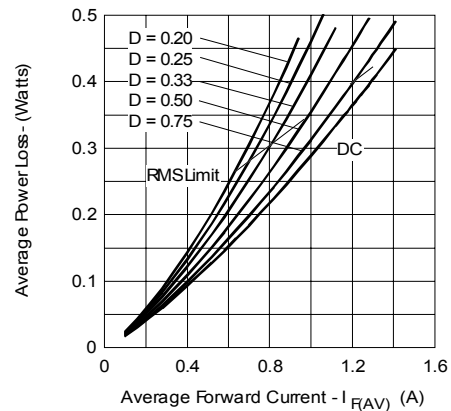


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

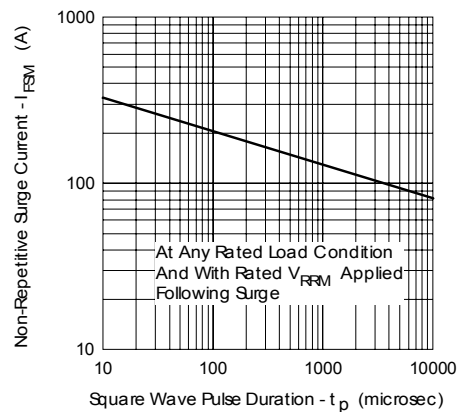


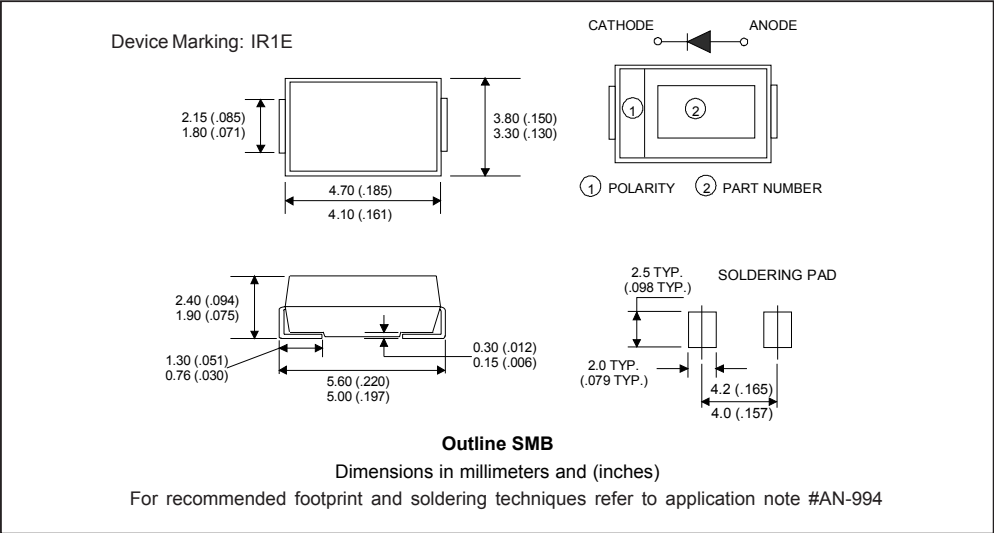
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;

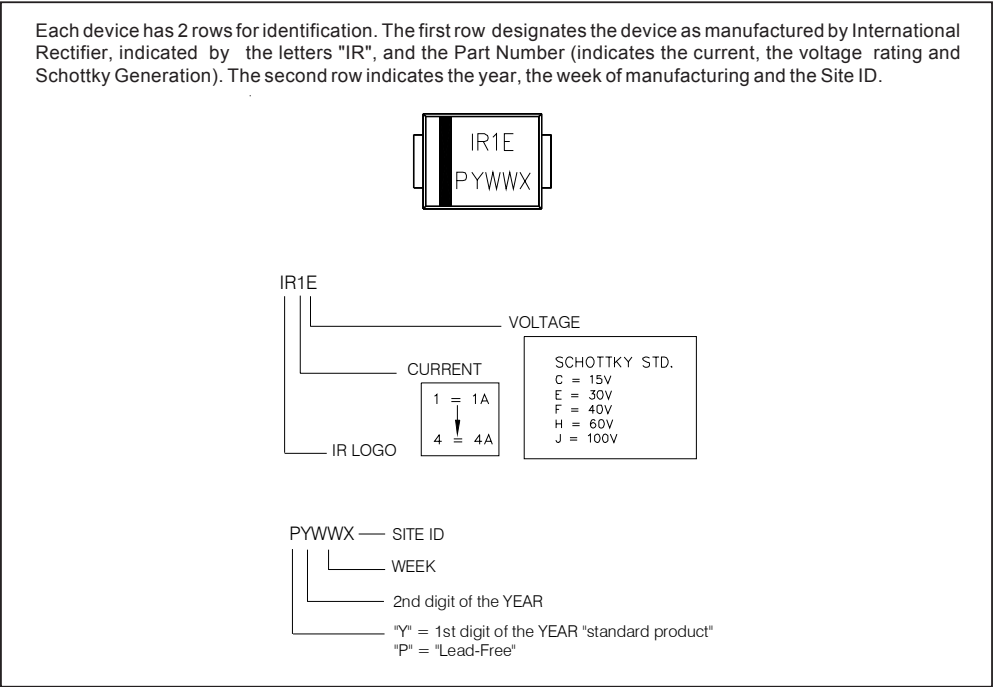
P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM}$ @ $(I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_{R1} (1 - D)$; I_{R1} @ V_{R1} = 80% rated V_R

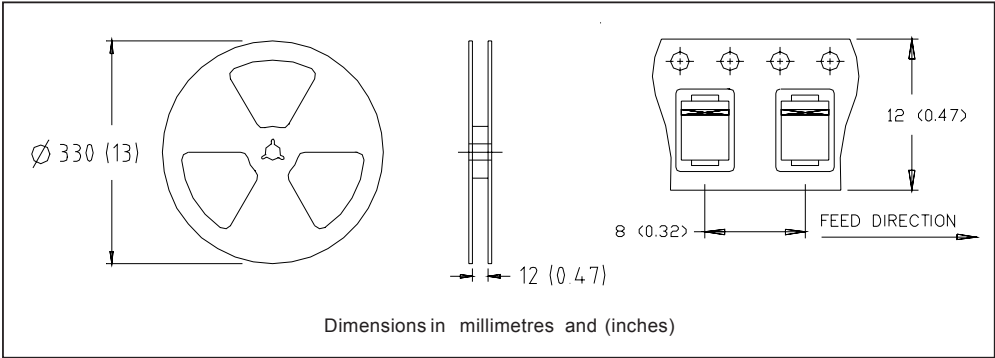
Outline Table



Marking & Identification



Tape & Reel Information



Ordering Information Table

Device Code					
10	B	Q	030	TR	PbF
1	2	3	4	5	6
1	- Current Rating				
2	- B = Single Lead Diode				
3	- Q = Schottky Q Series				
4	- Voltage Rating (030 = 30V)				
5	- • none = Box (1000 pieces) • TR = Tape & Reel (3000 pieces)				
6	- • none = Standard Production • PbF = Lead-Free				

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.



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